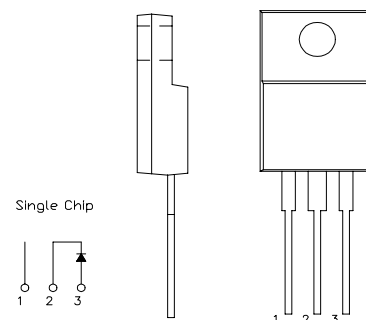


SBD Type : FSQ10A04B

OUTLINE DRAWING

FEATURES

- *Similar to TO-220AB Case
- *Fully Molded Isolation
- *Low Forward Voltage Drop
- *Low Power Loss,High Efficiency
- *High Surge Capability
- *Tj=150 °C operation



Maximum Ratings

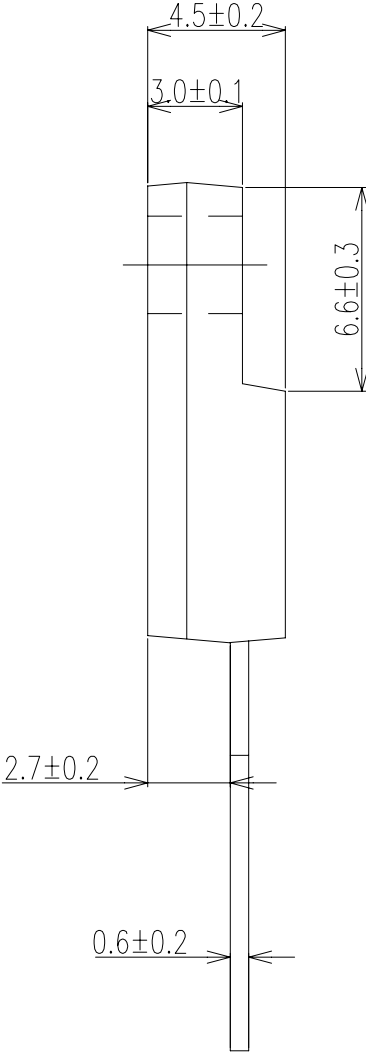
Approx Net Weight: 1.75g

Rating	Symbol	FSH10A04B			Unit
Repetitive Peak Reverse Voltage	V _{RRM}	40			V
Non-repetitive Peak Reverse Voltage	V _{RSM}	45			V
Average Rectified Output Current	I _O	10	Tc=119℃	50 Hz half Sine Wave Resistive Load	A
RMS Forward Current	I _{F(RMS)}	15.7			A
Surge Forward Current	I _{FSM}	180	50Hz Half Sine Wave ,1cycle Non-repetitive		A
Operating JunctionTemperature Range	T _{jw}	-40 to +150			℃
Storage Temperature Range	T _{stg}	-40 to +150			℃
Mounting torque	F _{tor}	recommended torque = 0.5			N•m

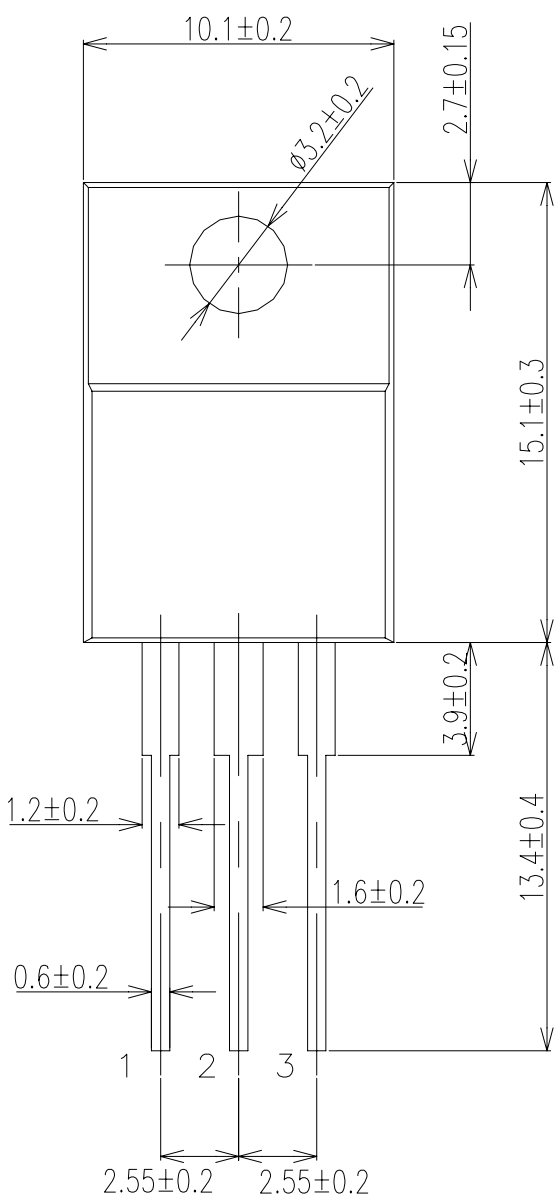
Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	$T_j= 25^{\circ}\text{C}, V_{RM}= V_{RRM}$	-	-	10	mA
Peak Forward Voltage	V_{FM}	$T_j= 25^{\circ}\text{C}, I_{FM}= 10 \text{ A}$	-	-	0.59	V
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	3	°C /W
	$R_{th(c-f)}$	Cace to Fin	-	-	1.5	°C /W

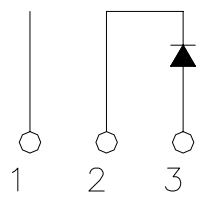
FSQ_A_B OUTLINE DRAWING (Dimensions in mm)



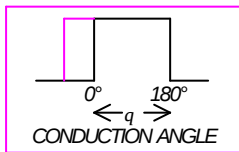
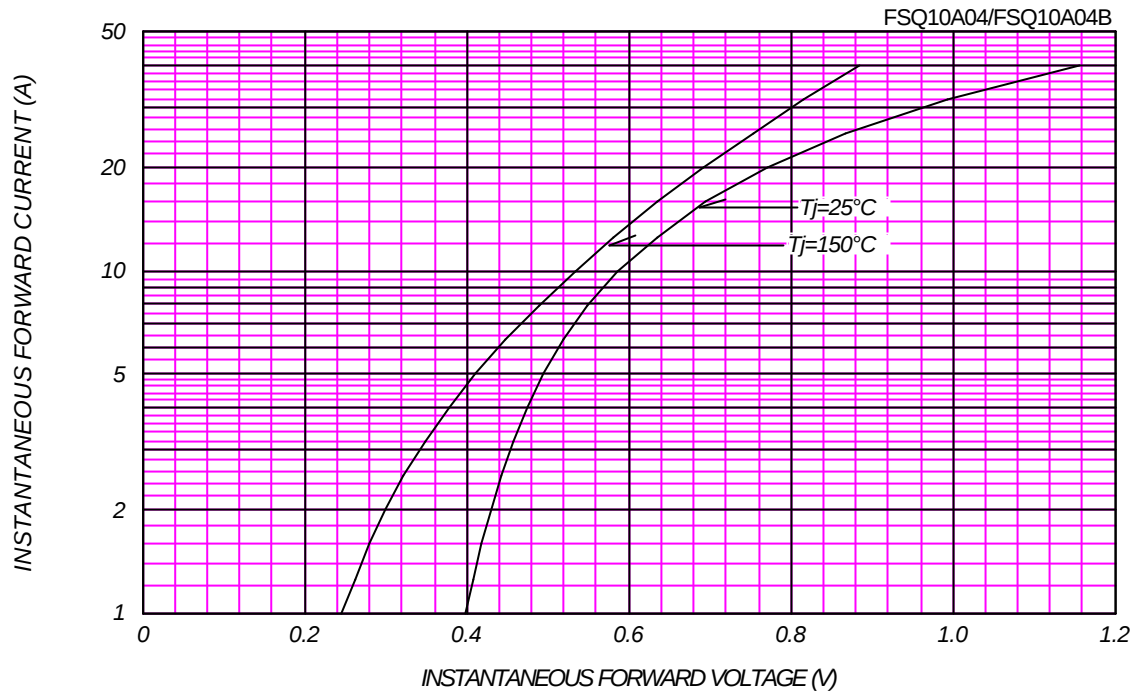
www.DataSheet4U.com



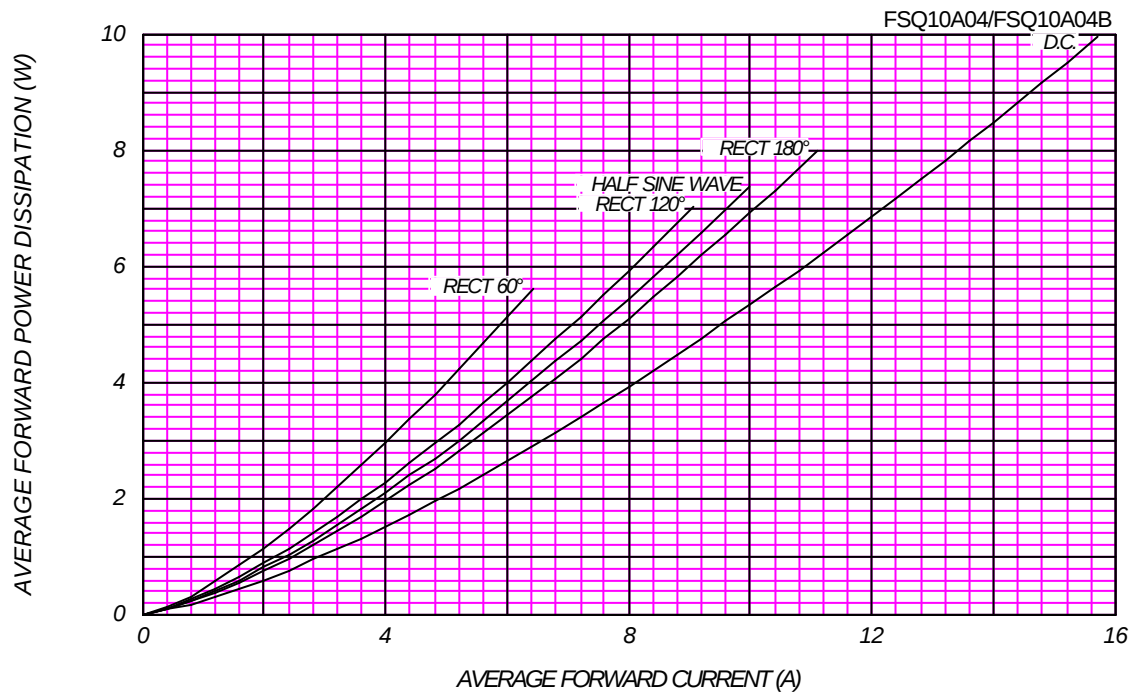
Single Chip



FORWARD CURRENT VS. VOLTAGE



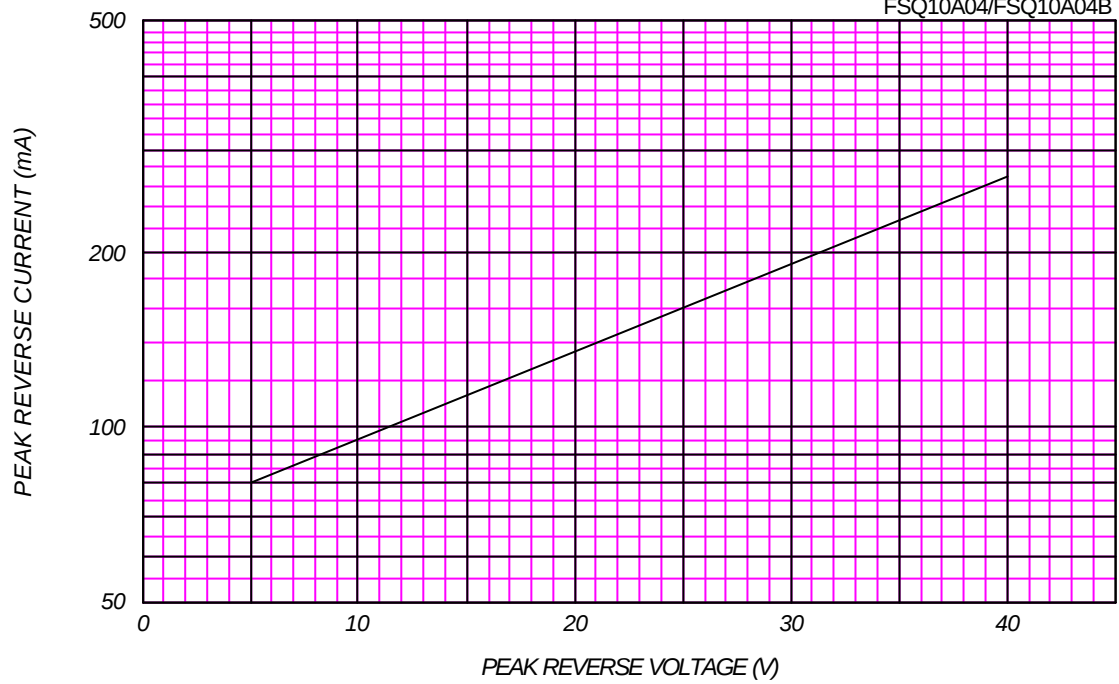
AVERAGE FORWARD POWER DISSIPATION



PEAK REVERSE CURRENT VS. PEAK REVERSE VOLTAGE

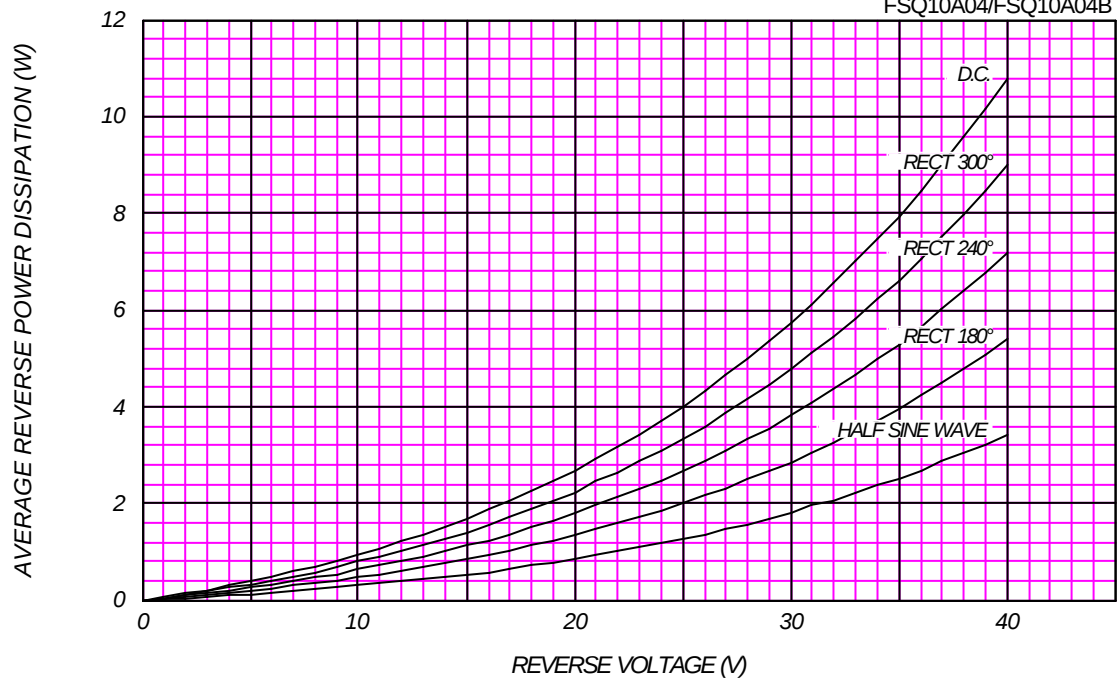
$T_j = 150^\circ\text{C}$

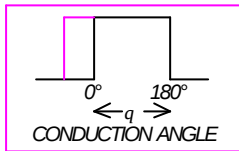
FSQ10A04/FSQ10A04B



AVERAGE REVERSE POWER DISSIPATION

FSQ10A04/FSQ10A04B

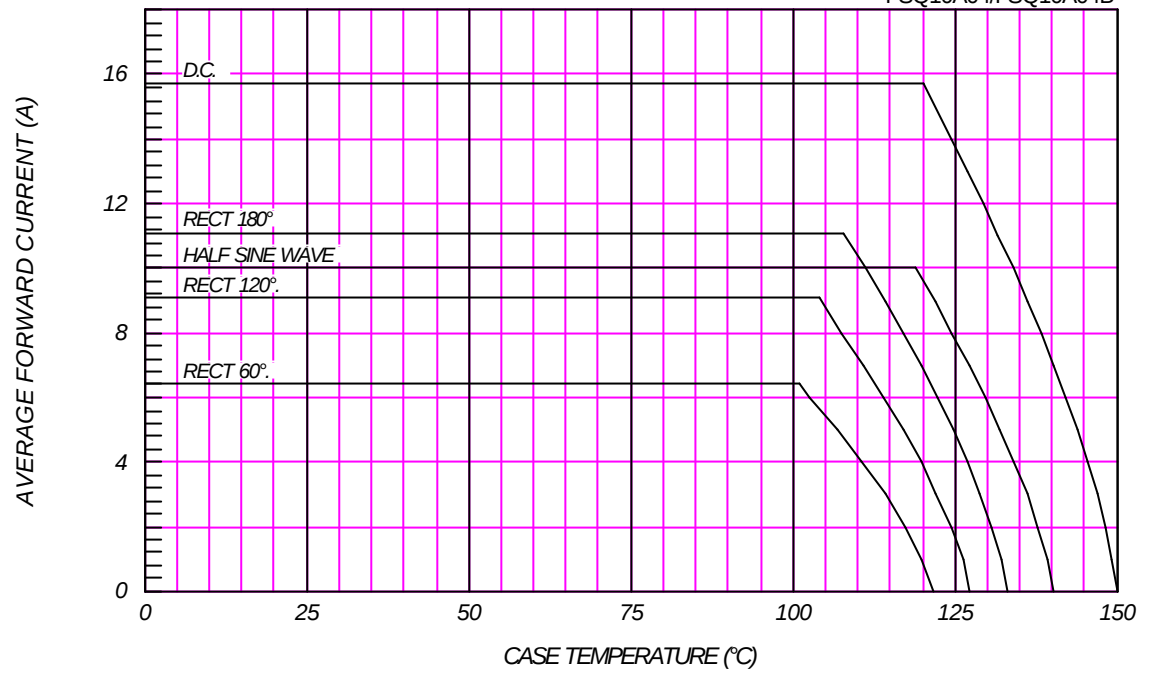




AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

 $V_{RM}=40V$

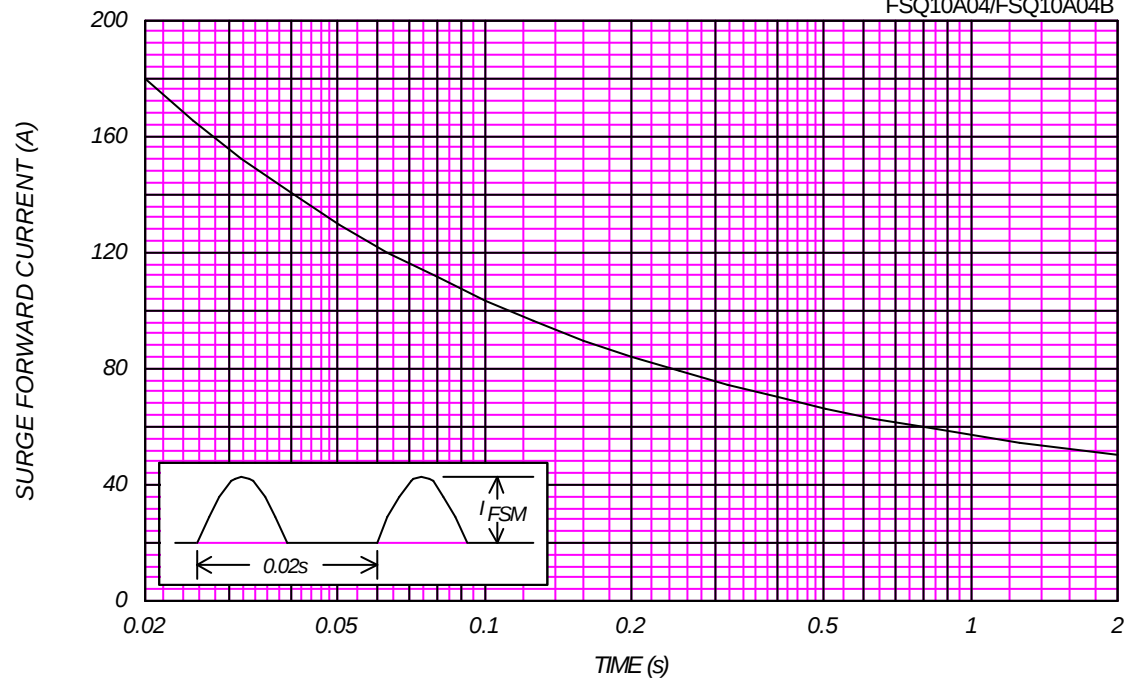
FSQ10A04/FSQ10A04B



SURGE CURRENT RATINGS

 $f=50\text{Hz}$, Half Sine Wave, Non-Repetitive, No Load

FSQ10A04/FSQ10A04B



JUNCTION CAPACITANCE VS. REVERSE VOLTAGE $T_j = 25^\circ\text{C}$, $V_m = 20\text{mV}_{\text{RMS}}$, $f = 100\text{kHz}$, Typical Value

FSQ10A04/FSQ10A04B

